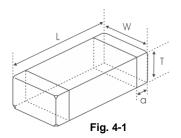


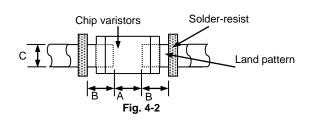
1. Electrical Characteristics

Please refer to Appendix A (Page 9~13).

- 1) Operating and storage temperature range (individual chip without packing): -55° C ~ +125 $^{\circ}$ C.
- 2) Storage temperature range (packaging conditions): -10 $^{\circ}$ C ~+40 $^{\circ}$ C RH 70% (Max.).

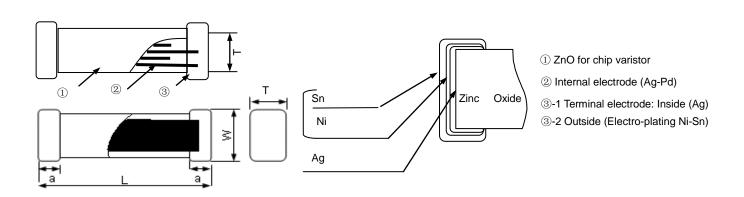
2. Shape and Dimensions





Unit: mm [inch]

Туре	L	W	Т	а	А	В	С
1005	1.0±0.15	0.5±0.15	0.5±0.15	0.25±0.1	0.45~0.55	0.40, 0.50	0.45~0.55
[0402]	[0.039±0.006]	[0.020±0.006]	[0.020±0.006]	[0.010±0.004]	0.45~0.55	0.40~0.50	0.45~0.55



Part Number	Max. Working Voltage		Varistor Voltage		Clamping Itage	Rated Sin Trans	-	Typical Capacitance
Test Condition	C C	0μA AC RMS	@1mA DC	8/20µs	ESD	Energy 10/1000µs	Peak Current 8/20µs	@0.5V _{rms} , 1MHz
Units	Volts	Volts	Volts	Volts	Volts	Joules	Amps	pF
Symbol	V_{WDC}	V_{WAC}	V_B	V _C *1	V _C *2	Ε _T	I _P	С
KBTR04D3	18.0	12.7	31.0-38.0	58	70	0.003	1	3

3. Test and Measurement Procedures

3.1 Test Conditions

3.1.1 Unless otherwise specified, the standard atmospheric conditions for measurement/test as:

a. Ambient Temperature: $20\pm15^{\circ}$ C.

b. Relative Humidity: 65±20%.

c. Air Pressure: 86kPa to 106kPa.

3.1.2 If any doubt on the results, measurements/tests should be made within the following limits:

a. Ambient Temperature: 20±2℃

b. Relative Humidity: 65±5%.

c. Air Pressure: 86kPa to 106kPa.

3.2 Visual Examination

a. Inspection Equipment: 20× magnifier.

3.3 Electrical Test

Items	Requirements	Test Methods and Remarks
3.3.1 Varistor Voltage at 1mA DC (V _B)	Refer to Appendix A	Measuring current: 1mA DC Duration: 0.2 to 2 sec
3.3.2 Capacitance (C)	Refer to Appendix A	Measure source: 0.5 V _{RMS} Test frequency: 1MHz.
3.3.3 Leakage Current (I _L)	Refer to Appendix A	Measuring voltage: Maximum DC working voltage
3.3.4 Clamping Voltage (V _C)	Refer to Appendix A	Measuring source: 8/20us waveform, ESD waveform

3.4 Reliability Test

Items	Requirements	Test Methods and Remarks		
3.4.1. Terminal	No removal or split of the termination or other defects shall occur.	Solder the chip to the testing jig (glass epoxy board shown in Fig.5.4.1-1) using eutectic solder. Then apply a force in the		
Strength	Chip	direction of the arrow. SN force for SDV1005 and 1608 series, 10N force for SDV2012 and 3216 series. Keep time: 10±1s.		
	Mounting Pad Glass Epoxy Board Fig.5.4.1-1			

3.4.2 Resistance to Flexure	No visible mechanical damage. Type a b c 1005[0402] 0.4 1.5 0.5 1608[0603] 1.0 3.0 1.2 2012[0805] 1.2 4.0 1.65 3216[1206] 2.2 5.0 2.0 Unit: mm [inch]	 Solder the chip to the test jig (glass epoxy board shown in Fig.3.4.2-1) using a eutectic solder. Then apply a force in the direction shown in Fig.3.4.2-2. Flexure: 2mm. Pressurizing Speed: 0.5mm/sec. Keep time: 30 sec. 		
3.4.3 Vibration	No visible mechanical damage. Cu pad Solder mask Glass Epoxy Board Fig. 3.4.3-1	Solder the chip to the testing jig (glass epoxy board shown in Fig.3.4.3-1) using eutectic solder. The chip shall be subjected to a simple harmonic motion having total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55 Hz. The frequency range from 10 to 55 Hz and return to 10 Hz shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3mutually perpendicular directions (total of 6 hours).		
3.4.4 Solderability	No visible mechanical damage. Wetting shall exceed 90% coverage.	 Solder temperature: 240±2°C Duration: 3 sec. Solder: Sn/3.0Ag/0.5Cu. Flux: 25% Resin and 75% ethanol in weight. 		
3.4.5 Resistance to Soldering Heat	No visible mechanical damage. Varistor voltage change: within ±10%.	 Solder temperature: 260±3°C Duration: 5 sec. The chip shall be stabilized at normal condition for 1~2hours before measuring. Solder: Sn/3.0Ag/0.5Cu. Flux: 25% Resin and 75% ethanol in weight. 		
3.4.6 Thermal Shock	① No visible mechanical damage. ② Varistor voltage change: within ±10%. 125℃ Ambient Temperature 30 min. 20sec. (max.)	 Temperature, Time: -55°C for 30±3 min→125°C for 30±3min. Transforming interval: 20sec. (max.) Tested cycle: 100 cycles. The chip shall be stabilized at normal condition for 1~2 hours before measuring. 		
3.4.7 Resistance to Low Temperature	No visible mechanical damage. Varistor voltage change: within ±10%.	 Temperature: -55±2°C Duration: 1000⁺²⁴ hours. The chip shall be stabilized at normal condition for 1~2 hours before measuring. 		
3.4.8 Resistance to High Temperature	 No visible mechanical damage. Varistor voltage change: within ±10%. 	 Temperature: 125±2°C. Duration: 1000⁺²⁴ hours. The chip shall be stabilized at normal condition for 1~2 hours before measuring. 		
3.4.9 Damp Heat (Steady States)	 No visible mechanical damage. Varistor voltage change: within ±10%. 	 Temperature: 60±2℃ Humidity: 90% to 95% RH. Duration: 1000⁺²⁴ hours. The chip shall be stabilized at normal condition for 1~2 hours before measuring. 		

3.4.10 Loading Under Damp Heat 3.4.11 Loading at High Temperature	 No visible mechanical damage. Varistor voltage change: within ±10%. No visible mechanical damage. Varistor voltage change: within ±10%. 	 Temperature: 60±2°C Humidity: 90% to 95% RH. Duration: 1000+24 hours. Applied voltage: DC Working Voltage. The chip shall be stabilized at normal condition for 1~2 hours before measuring. Temperature: 125±2°C Duration: 1000+24 hours. Applied voltage: DC Working Voltage.
(Life Test)		The chip shall be stabilized at normal condition for 1~2 hours before measuring.
3.4.12 Maximum Surge Current	No visible mechanical damage. Varistor voltage change: within ±10%. IEC61000-4-5 standard 1.2/50us-8/20us voltage-current combination pulse	 Temperature: 25±5°C Humidity: 30% to 65% RH. Number of hit: each 1 time of +/- polarity. Pulse waveform: 8/20 us. Applied current: maximum surge current (I_P). The chip shall be stabilized at normal condition for 1~2 hours before measuring.
3.4.13 Maximum Surge Energy	No visible mechanical damage. Varistor voltage change: within ±10%. IEC61000-4-5 standard 10/1000us current pulse	 Temperature :25±5℃ Humidity: 30% to 65% RH. Number of hit: 1 time. Pulse waveform: 10/1000 us. Applied energy: maximum surge energy (E_T). The chip shall be stabilized at normal condition for 1~2 hours before measuring.
3.4.14 ESD Life	No visible mechanical damage. Varistor voltage change: within ±10%. IEC61000-4-2 standard ESD gun C=150pF R=330Ω	 Discharge: Contact discharge. Voltage: 8000V (Level 4). Polarity: +, Number: 10 times within 10 sec. The chip shall be stabilized at normal condition for 1~2 hours before measuring.
3.4.15 ESD Test	No visible mechanical damage. Varistor voltage change: within ±10%. IEC61000-4-2 standard ESD gun C=150pF R=330Ω	 Discharge: Air discharge. Voltage: 15000V (Special level). Polarity: +, - Number: 10 times within 10 sec. The chip shall be stabilized at normal condition for 1~2 hours before measuring.

4. Recommended Soldering Technologies

4.1 Reflow Profile:

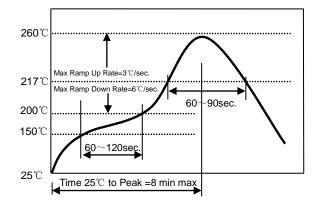
△ Preheat condition: 150 ~200 °C/60~120sec.

△ Allowed time above 217C: 60~90sec.

△ Max temp: 260°C

△ Max time at max temp: 10sec.
 △ Solder paste: Sn/3.0Ag/0.5Cu
 △ Allowed Reflow time: 2x max

[Note: The reflow profile in the above table is only for qualification and is not meant to specify board assembly profiles. Actual board assembly profiles must be based on the customer's specific board design, solder paste and process, and should not exceed the parameters as the Reflow profile shows.]

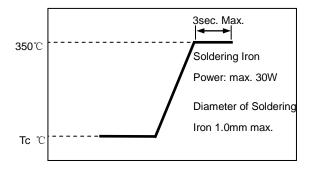


4.2 Iron Soldering Profile.

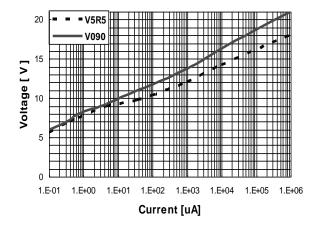
 \triangle Iron soldering power: Max.30W \triangle Pre-heating: 150 $^{\circ}$ C / 60 sec.

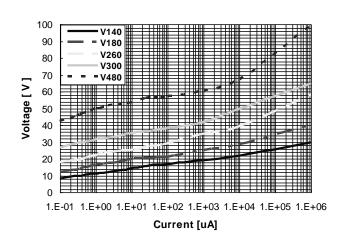
△ Soldering Tip temperature: 350°C Max.

[Note: Take care not to apply the tip of the soldering iron to the terminal electrodes.]



5.characteristic curves of chip varistor





单击下面可查看定价,库存,交付和生命周期等信息

<u>>>KUU(永裕泰)</u>